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Sheet 1 of 2	Application Number		Unknown	
	Filing Date		Herewith	
	First Named Inventor		Mark Lemkin	
	Group Art Unit		Unknown	
	Examiner Name		Unknown	
	Attorney Docket Number		AIMI-01841US0	

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08/31/01

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Examiner Signature		Date Considered	1/16/03
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Sheet	2	of	2	Application Number	Unknown
				Filing Date	Herewith
				First Named Inventor	Mark Lemkin
				Group Art Unit	Unknown
				Examiner Name	Unknown
				Attorney Docket Number	AIMI-01841US0

OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
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Examiner Signature		Date Considered	01/16/03
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